



SamHop Microelectronics Corp.

STA4470

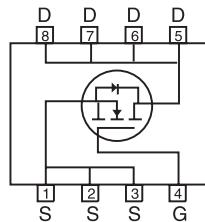
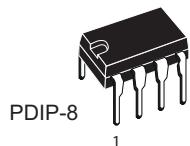
Ver 1.0

N-Channel Enhancement Mode Field Effect Transistor

PRODUCT SUMMARY		
V _{DSS}	I _D	R _{DSON} (mΩ) Max
40V	11A	12 @ V _{GS} =10V
		16 @ V _{GS} =4.5V

FEATURES

- Super high dense cell design for low R_{DSON}.
- Rugged and reliable.
- Surface Mount Package.



ABSOLUTE MAXIMUM RATINGS (T_A=25°C unless otherwise noted)

Symbol	Parameter		Limit	Units
V _{DS}	Drain-Source Voltage		40	V
V _{GS}	Gate-Source Voltage		±20	V
I _D	Drain Current-Continuous ^a	T _A =25°C	11	A
		T _A =70°C	8.9	A
I _{DM}	-Pulsed ^b		55	A
P _D	Maximum Power Dissipation ^a	T _A =25°C	2.5	W
		T _A =70°C	1.6	W
T _J , T _{STG}	Operating Junction and Storage Temperature Range		-55 to 150	°C

THERMAL CHARACTERISTICS

R _{θ JA}	Thermal Resistance, Junction-to-Ambient ^a	50	°C/W
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Details are subject to change without notice.

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ELECTRICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
OFF CHARACTERISTICS						
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =250uA	40			V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =32V , V _{GS} =0V			1	uA
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±20V , V _{DS} =0V			±100	nA
ON CHARACTERISTICS ^b						
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250uA	1.0	2.0	3	V
R _{D(S(ON))}	Drain-Source On-State Resistance	V _{GS} =10V , I _D =11A		10	12	m ohm
		V _{GS} =4.5V , I _D =9.6A		12	16	m ohm
g _{FS}	Forward Transconductance	V _{DS} =5V , I _D =11A		26.5		S
DYNAMIC CHARACTERISTICS ^c						
C _{ISS}	Input Capacitance	V _{DS} =20V,V _{GS} =0V f=1.0MHz		1720		pF
C _{OSS}	Output Capacitance			230		pF
C _{RSS}	Reverse Transfer Capacitance			145		pF
SWITCHING CHARACTERISTICS ^c						
t _{D(ON)}	Turn-On Delay Time	V _{DD} =20V I _D =1A V _{GS} =10V R _{GEN} =3.3 ohm		22		ns
t _r	Rise Time			23		ns
t _{D(OFF)}	Turn-Off Delay Time			65		ns
t _f	Fall Time			30		ns
Q _g	Total Gate Charge	V _{DS} =20V,I _D =11A,V _{GS} =10V		25		nC
		V _{DS} =20V,I _D =11A,V _{GS} =4.5V		12		nC
Q _{gs}	Gate-Source Charge	V _{DS} =20V,I _D =11A, V _{GS} =10V		2.5		nC
Q _{gd}	Gate-Drain Charge			5.5		nC
DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS						
I _s	Maximum Continuous Drain-Source Diode Forward Current				1.7	A
V _{SD}	Diode Forward Voltage	V _{GS} =0V,I _s =1.7A		0.74	1.2	V
Notes						
a.Surface Mounted on FR4 Board,t ≤ 10sec.						
b.Pulse Test:Pulse Width ≤ 300us, Duty Cycle ≤ 2%.						
c.Guaranteed by design, not subject to production testing.						

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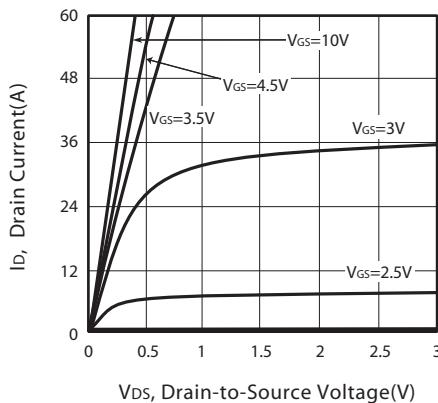


Figure 1. Output Characteristics

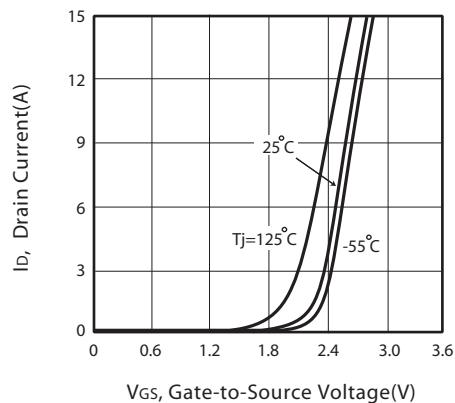


Figure 2. Transfer Characteristics

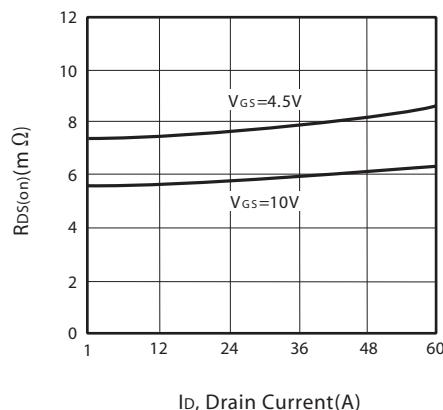


Figure 3. On-Resistance vs. Drain Current and Gate Voltage

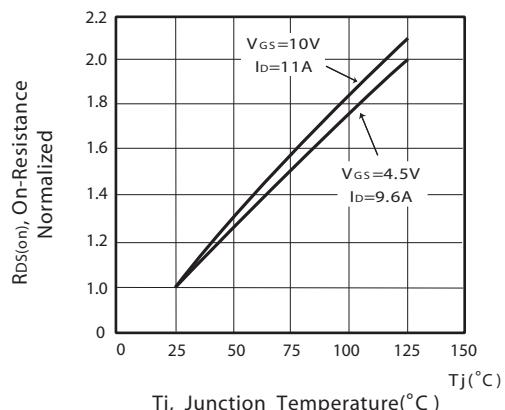


Figure 4. On-Resistance Variation with Drain Current and Temperature

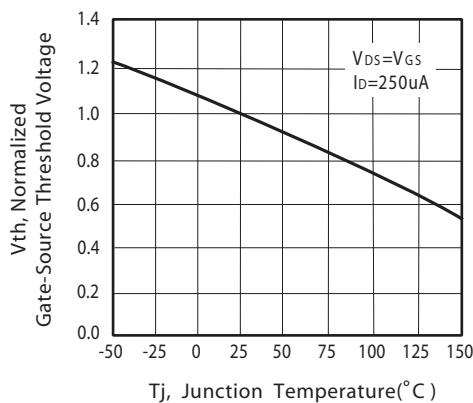


Figure 5. Gate Threshold Variation with Temperature

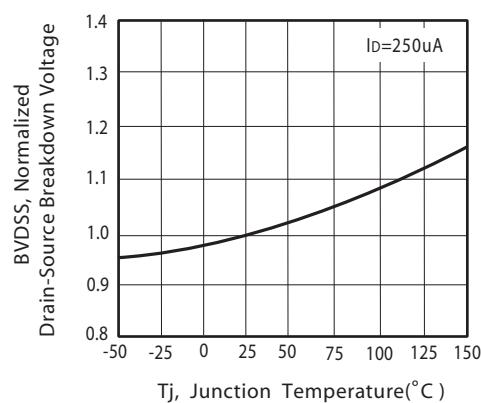


Figure 6. Breakdown Voltage Variation with Temperature

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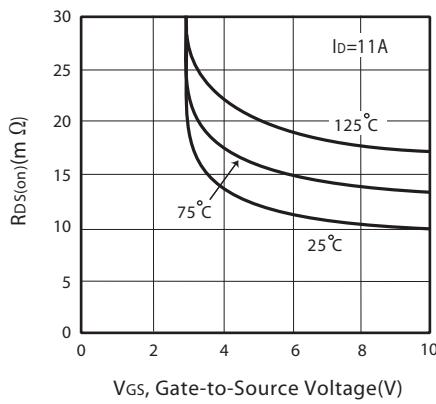


Figure 7. On-Resistance vs.
Gate-Source Voltage

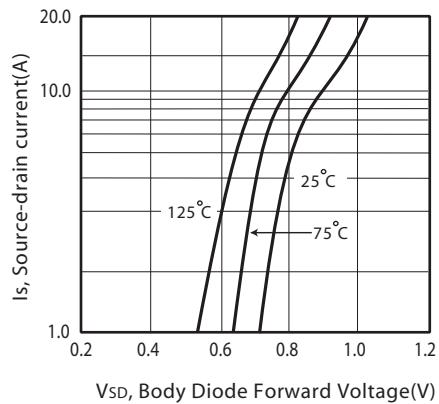


Figure 8. Body Diode Forward Voltage
Variation with Source Current

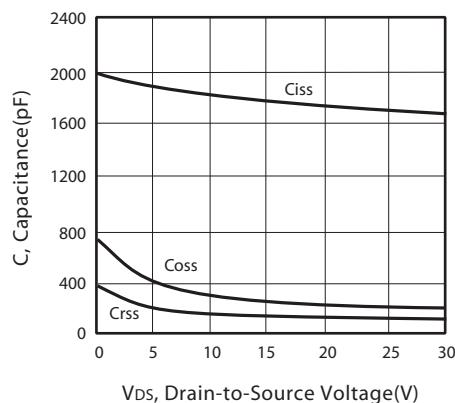


Figure 9. Capacitance

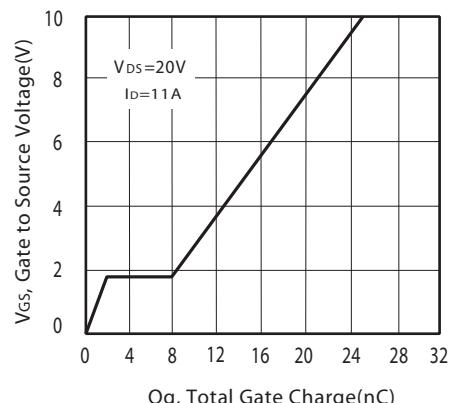


Figure 10. Gate Charge

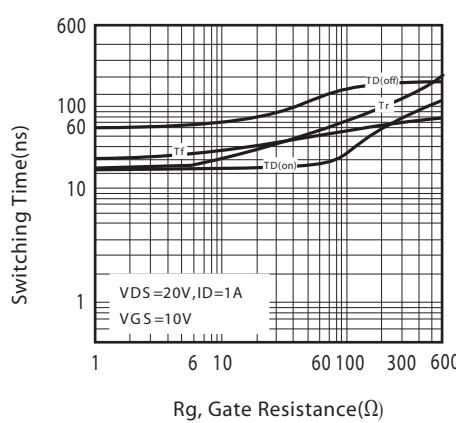


Figure 11. switching characteristics

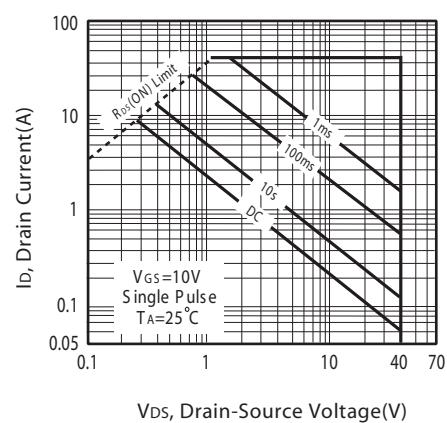


Figure 12. Maximum Safe Operating Area

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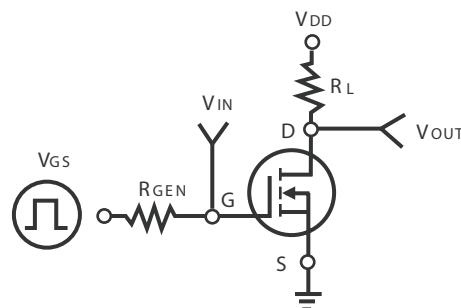


Figure 13. Switching Test Circuit

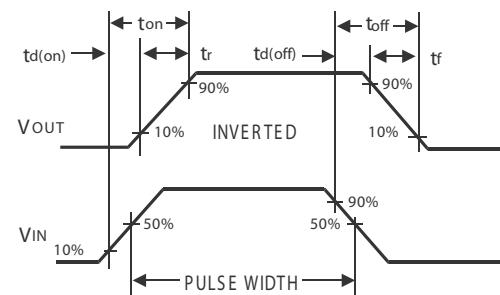


Figure 14. Switching Waveforms

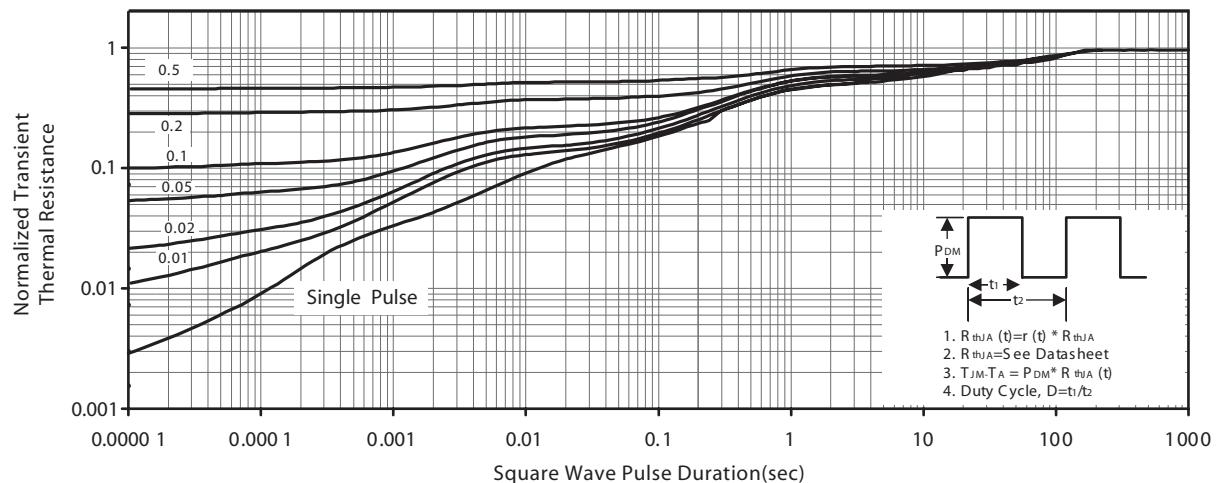
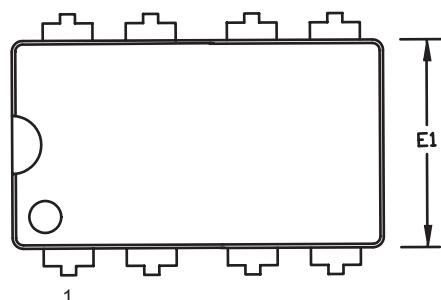


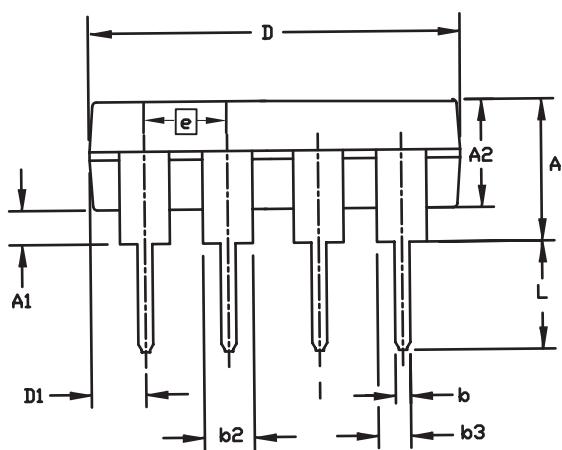
Figure 15. Normalized Thermal Transient Impedance Curve

PACKAGE OUTLINE DIMENSIONS

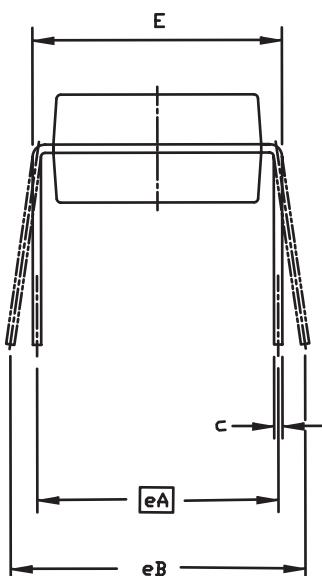
PDIP-8



TOP VIEW



FRONT VIEW



SIDE VIEW

SYMBOL	INCHES			MILLIMETERS		
	MIN	NOM	MAX	MIN	NOM	MAX
A	.145	.172	.200	3.68	4.37	5.08
A1	.020	-	-	0.51	-	-
A2	.125	.130	.135	3.18	3.30	3.43
b	.015	.018	.021	0.38	0.46	0.53
c	.009	.012	.014	0.23	0.30	0.36
b2	.045	.060	.070	1.14	1.52	1.78
b3	.030	.039	.045	0.76	0.99	1.14
L	.125	.132	.140	3.18	3.35	3.56
e	.090	.100	.110	2.29	2.54	2.79
D	.373	.386	.400	9.47	9.80	10.16
D1	.030	.045	.060	0.76	1.14	1.52
E	.300	.310	.320	7.62	7.87	8.13
E1	.245	.250	.255	6.22	6.35	6.48
eA	.280	-	-	7.11	-	-
eB	.310	.325	.365	7.87	8.26	9.27